

# Surface Mount General Purpose Silicon Rectifiers Forward Current - 1 A

#### **FEATURES**

- •For surface mounted applications
- Low profile package
- Glass Passivated Chip Junction
- Ideal for automated placement
- Lead free in comply with EU RoHS 2011/65/EU directives

#### **PINNING**

| PIN | DESCRIPTION |
|-----|-------------|
| 1   | Cathode     |
| 2   | Anode       |



Top View Simplified outline SOD-123FL and symbol

#### **MECHANICAL DATA**

Case: SOD-123FL

•Terminals: Solderable per MIL-STD-750, Method 2026

Approx. Weight: 15mg / 0.00053oz

#### **Maximum Ratings and Electrical characteristics**

Ratings at 25 °C ambient temperature unless otherwise specified.

Single phase half-wave 60 Hz, resistive or inductive load, for capacitive load current derate by 20 %.

| Parameter  | Symbols            | 1N4007W    | Units  |  |
|--|--------------------|------------|--------|--|
| Maximum Repetitive Peak Reverse Voltage  | $V_{RRM}$          | 1000       | V      |  |
| Maximum RMS voltage  | V <sub>RMS</sub>   | 700        | V      |  |
| Maximum DC Blocking Voltage  | V <sub>DC</sub>    | 1000       | V      |  |
| Maximum Average Forward Rectified Current at $T_c = 125$ °C  | I <sub>F(AV)</sub> | 1          | А      |  |
| Peak Forward Surge Current 8.3 ms Single Half<br>Sine Wave Superimposed on Rated Load                  | I <sub>FSM</sub>   | 30         | А      |  |
| Maximum Instantaneous Forward Voltage at 1 A   | V <sub>F</sub>     | 1.1        | \<br>\ |  |
| Maximum DC Reverse Current T <sub>a</sub> = 25 °C at Rated DC Blocking Voltage T <sub>a</sub> = 125 °C | I <sub>R</sub>     | 5<br>50    | μA     |  |
| Typical Junction Capacitance (1)   | C <sub>j</sub>     | 8(TYP.)    |        |  |
| Typical Thermal Resistance (2)   | R <sub>θJA</sub>   | 90         |        |  |
| Operating and Storage Temperature Range  | $T_{j},T_{stg}$    | -55 ~ +150 |        |  |

<sup>( 1 )</sup> Measured at 1 MHz and applied reverse voltage of 4 V D.C

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<sup>(</sup> 2 ) P.C.B. mounted with 2.0" X 2.0" (5 X 5 cm) copper pad areas.



Fig.1 Forward Current Derating Curve

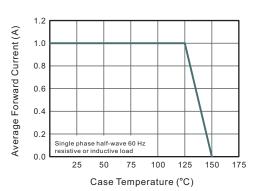


Fig.2 Typical Instaneous Reverse Characteristics

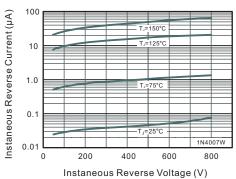


Fig.3 Typical Forward Characteristic

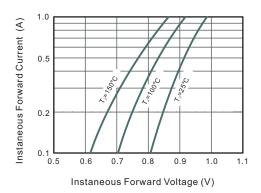


Fig.4 Typical Junction Capacitance

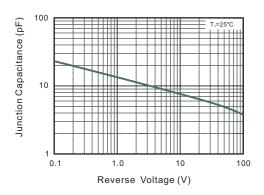
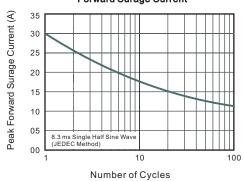


Fig.5 Maximum Non-Repetitive Peak Forward Surage Current



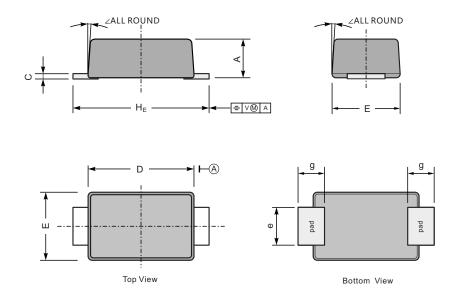
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## PACKAGE OUTLINE

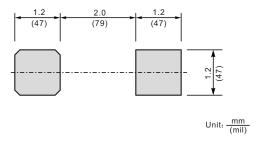
## Plastic surface mounted package; 2 leads

SOD-123FL



| UNIT  |     | Α   | С    | D   | Е   | е   | g   | H <sub>E</sub> | ∠    |
|-------|-----|-----|------|-----|-----|-----|-----|----------------|------|
| mm    | max | 1.1 | 0.20 | 2.9 | 1.9 | 1.1 | 0.9 | 3.8            | . 7° |
| ''''' | min | 0.9 | 0.12 | 2.6 | 1.7 | 0.8 | 0.7 | 3.5            |      |
| mil   | max | 43  | 7.9  | 114 | 75  | 43  | 35  | 150            | ,    |
|       | min | 35  | 4.7  | 102 | 67  | 31  | 28  | 138            |      |

# The recommended mounting pad size



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